Microsemi Corp. The diode expert

SANTA ANA, CA

SCOTTSDALE, AZ For more information call: (602) 941-6300

#### Features

(\*) • Available as screened equivalents using prefixes noted below: MX as JTX equivalent MV as JTXV equivalent MS as JANS equivalent

 (†) • Available in chip form using prefixes noted below: CH as Aluminum on top, gold on back CNS as Titanium Nickel Silver on top and bottom
• Provides essentially constant current over a wide voltage range.
• High Source Impedance

### **Maximum Ratings**

Operating Temperature:  $-55^{\circ}$  C to  $+175^{\circ}$  C Storage Temperature:  $-55^{\circ}$  C to  $+175^{\circ}$  C DC Power Dissipation:  $475 \text{ mW} @ T_{L} \le 75^{\circ}$ C Power Derating:  $3.1 \text{ mW}^{\circ}$  C @  $T_{L} > 75^{\circ}$  C Peak Operating Voltage: 100 Volts

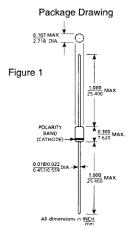
## Electrical Characteristics @ 25°C unless otherwise specified.

TYPE NUMBER	REGULATOR CURRENT Ip (mA) @ V <sub>5</sub> = 25V			MINIMUM       DYNAMIC       IMPEDANCE       @ V <sub>5</sub> - 25 V       Z <sub>5</sub> (MΩ)	MINIMUM KNEÉ IMPEDANCE & V <sub>K</sub> - 6.0 V	MAXIMUM LIMITING VOLTAGE 8 IL = 0.8 Ip (min) VI (VOLTS)
	NOM	MIN	МАХ	(Note 1)	Z <sub>K</sub> (MΩ) (Note 2)	VL (VOLIS)
1N5283	0.22	0.198	0.242	25.0	2.75	1.00
1N5284	0.24	0.216	0.264	19.0	2.35	1.00
1N5285	0.27	0.243	0.297	14.0	1.95	1.00
1N5286	0.30	0.270	0.330	09.0	1.60	1.00
1N5287	0.33	0.297	0.363	06.6	1.35	1.00
1N5288	0.39	0.351	0.429	4.10	1.00	1.05
1N5289	0.43	0.387	0.473	3.30	0.870	1.05
1N5290	0.47	0.423	0.517	2.70	0.750	1.05
1N5291	0.56	0.504	0.616	1.90	0.560	1.10
1N5292	0.62	0.558	0.682	1.55	0.470	1.13
1N5293	0.68	0.612	0.748	1.35	0.400	1.15
1N5294	0.75	0.675	0.825	1.15	0.335	1.20
1N5295	0.82	0.738	0.902	1.00	0.290	1.25
1N5296	0.91	0.819	1.001	0.880	0.240	1.29
1N5297	1.00	0.900	1,100	0.800	0.205	1.35
1N5298	1.10	0.990	1.210	0.700	0.180	1.40
1N5299	1.20	1.06	1.32	0.640	0.155	1.45
1N5300	1.30	1.17	1.43	0.580	0.135	1.50
1N5301	1.40	1.26	1.54	0.540	0.115	1.55
1N5302	1.50	1.35	1.65	0.510	0.105	1.60
1N5303	1.60	1.44	1.76	0.475	0.092	1.65
1N5304	1.80	1.62	1.98	0.420	0.074	1.75
1N5305	2.00	1.80	2.20	0.395	0.061	1.85
1N5306	2.20	1.98	2.42	0.370	0.052	1.95
1N5307	2.40	2.16	2.64	0.345	0.044	2.00
1N5308	2.70	2.43	2.97	0.320	0.035	2.15
1N5309	3.00	2.70	3.30	0.300	0.029	2.25
1N5310	3.30	2.97	3.63	0.280	0.024	2.35
1N5311	3.60	3.24	3.96	0.265	0.020	2.50
1N5312	3.90	3.51	4.29	0.255	0.017	2.60
1N5313	4.30	3.87	4.73	0.245	0.014	2.75
1N5314	4,70	4.23	5.17	0.235	0.012	Z.90

NOTE 1:  $Z_S$  is derived by superimposing a 90Hz rms signal equal to 10% of  $V_S$  on  $V_S$ . NOTE 2:  $Z_K$  is derived by superimposing a 90Hz rms signal equal to 10% of  $V_K$  on  $V_K$ .

## M\*5283 thru M\*5314 and C†5283 thru C†5314

HIGH RELIABILITY CURRENT REGULATOR DIODES



### Mechanical Characteristics

**CASE:** Hermetically sealed glass case. DO-7 outline.

LEAD MATERIAL: Dumet.

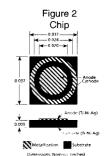
LEAD FINISH: Tin plate.

# **THERMAL RESISTANCE:** 300° C/W (Typical) junction to ambient.

**POLARITY:** Cathode end is banded.

WEIGHT: 0.2 grams

#### MOUNTING POSITION: Any.



## M\*5283 thru M\*5314 and C†5283 thru C†5314

FIGURE 3 Typical Current Regulator Characteristics

lp & Zs @ ∀s

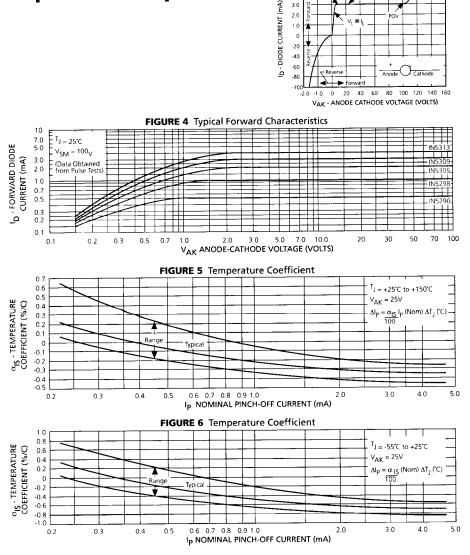
ø V,

5.0

4.0

3.0 2.0

1.0 \*



#### SYMBOLS AND DEFINITIONS IL - Limiting Current: 80% of Ip minimum used to determine Limiting Voltage, VL.

- ID Diode Current
- Pinch-off Current: Regulator current at specified Test Voltage, VS. Ip is sometimes also identified as IS. ١p
- Peak Operating Voltage: Maximum voltage to be applied to device. POV
- VAK Anode-to-cathode Voltage - Current Temperature Coefficient. αIS
- $V_{\mbox{K}}$  Knee Impedance Test Voltage: Specified voltage used to establish Knee Impedance,  $Z_{\mbox{K}}$
- VL Limiting voltage: Measured at IL, VL, together with Knee ac Impedance, ZK, indicates the Knee characteristics of the device.
- Test Voltage: Voltage at which Ip and ZS are specified. ٧s
- ZK Knee AC Impedance at Test Voltage: To test for ZK, a 90 Hz signal vK with rms value equal to 10% of test voltage VK is superimposed on VK: ZK = VK/IK where iK is the resultant ac current due to VK. To provide the most constant current from the diode, ZK should be as high as possible; therefore, a minimum value of ZK is specified.
- Z<sub>S</sub> AC Impedance at Test Voltage: Specified as a minimum value. To test for Z<sub>S</sub>, a 90 Hz signal v<sub>S</sub> with rms value equal to 10% of test voltage, V<sub>S</sub>. is superimposed on V<sub>S</sub>:  $Z_S = v_S/i_S$  where is is the resultant ac current due to  $v_S$ .

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1N5310 1N5287 1N5306 1N5305 1N5284 1N5311 1N5313